RT-P10C85-C(I)00
10Gb/s SFP+ 850nm Duplex 300m Transceiver

Product Features

- Up to 10Gb/s data links
- VCSEL laser transmitter and PIN photo-detector
- Up to 300m transmission on OM3 MMF
- Hot-pluggable SFP+ footprint
- Duplex LC/UPC type pluggable optical interface
- Low power dissipation
- Metal enclosure, for lower EMI
- RoHS compliant and lead-free
- Single +3.3V powersupply
- Support Digital Diagnostic Monitoring interface
- Electrical interface compliant to SFF-8431
- Case operating temperature
  Commercial: 0°C to +70°C
  Industrial: -40°C to +85°C

Applications

- 10GBASE-SR/SW Ethernet
- SONET OC-192 / SDH STM-64
- 10G Fibre Channel

Ordering Information

Part Number	Description
RT-P10C85-C(I)00	10Gb/s SFP+ 850nm Duplex 300m Transceiver

For More Information:
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Product Description

The SFP+ transceivers are high performance, cost effective modules supporting multi data-rate of 10Gbps and 300m transmission distance with MMF. The transceivers are compatible with SFP+ Multi-Source Agreement (MSA) ， For further information, please refer to SFP+ MSA.

Product Selection

Part Number	Operating Case temperature	DDMI
RT-P10C85-C00	Commercial(0~70℃)	Yes
RT-P10C85-I00	Industrial (-40~85℃)	Yes

Pin Descriptions

Pin	Symbol	Name/Description	NOTE
1	VEET	Module transmitter ground	1
2	Fault	Module transmitter Fault	2
3	Disable	Transmitter Disable; Turns off transmitter laser output	3
4	SDL	2 wire serial interface data input/output (SDA)	4
5	SCL	2 wire serial interface clock input (SCL)	4
6	MOD-ABS	Module Absent, connect to VeeR or VeeT in the module	2
7	RS0	Rate select0: module inputs and are pulled low to VeeT with >30 kΩ resistorsin the module.	
8	LOS	Receiver Loss of Signal Indication	
9	RS1	Rate select1: module inputs and are pulled low to VeeT with >30 kΩ resistorsin the module.	
10	VeeR	Module receiver ground	1
11	VeeR	Module receiver ground	1
12	RD-	Receiver inverted data out put	
13	RD+	Receiver non-inverted data out put	
14	VeeR	Module receiver ground	1
15	VccR	Module receiver 3.3V supply	
16	VccT	Module transmitter 3.3V supply	
17	VeeT	Module transmitter ground	1
18	TD+	Transmitter non-inverted data out put	
19	TD-	Transmitter inverted data out put	
20	VeeT	Module transmitter ground	1

Notes:

1. The module ground pins shall be isolated from the module case.
2. This pin is an open collector/drain output pin and shall be pulled up with 4.7K-10Kohms to Host_Vcc on the host board.
3. This pin shall be pulled up with 4.7K-10Kohms to VccT in the module.
4. This pin is an open collector/drain output pin and shall be pulled up with 4.7K-10Kohms to Host_Vcc on the host board.

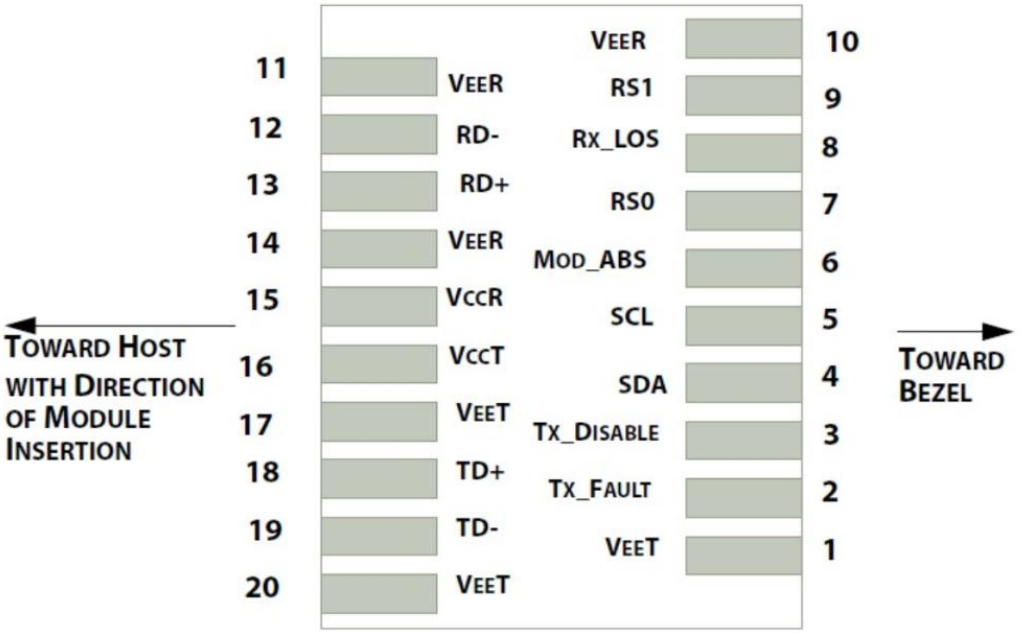


Figure2. Pin out of Connector Block on Host Board

Absolute Maximum Ratings

Parameter	Symbol	Min.	Typ.	Max.	Unit	Note
Storage Temperature	Ts	-50		+95	℃	
Relative Humidity	RH	5		95	%	
Power Supply Voltage	VCC	-0.3		+4	V	

Recommended Operating Conditions

Parameter	Symbol	Min.	Typ.	Max.	Unit	Note
Case Operating Temperature	Tc	0		70	℃	Commercial
		-40		85	℃	Industrial
Power Supply Voltage	Vcc	3.14	3.3	3.47	V	
Power Supply Current	Icc			300	mA	
Data Rate	BR		10.31		Gbps	
50/125um MMF	Lmax			300	m	

Electrical Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Note
Transmitter						
Tx Disable Input-High	VDISH	2		Vcc+0.3	V	
Tx Disable Input-Low	VDISL	0		0.8	V	
Tx Fault Input-High	VTxFH	2		Vcc+0.3	V	
Tx Fault Input-Low	VTxFL	0		0.8	V	
Receiver						
LOSS -High	V_{LOSH}	2		Vcc+0.3	V	
LOSS -Low	V_{LOSL}	0		0.8	V	

Optical Characteristics

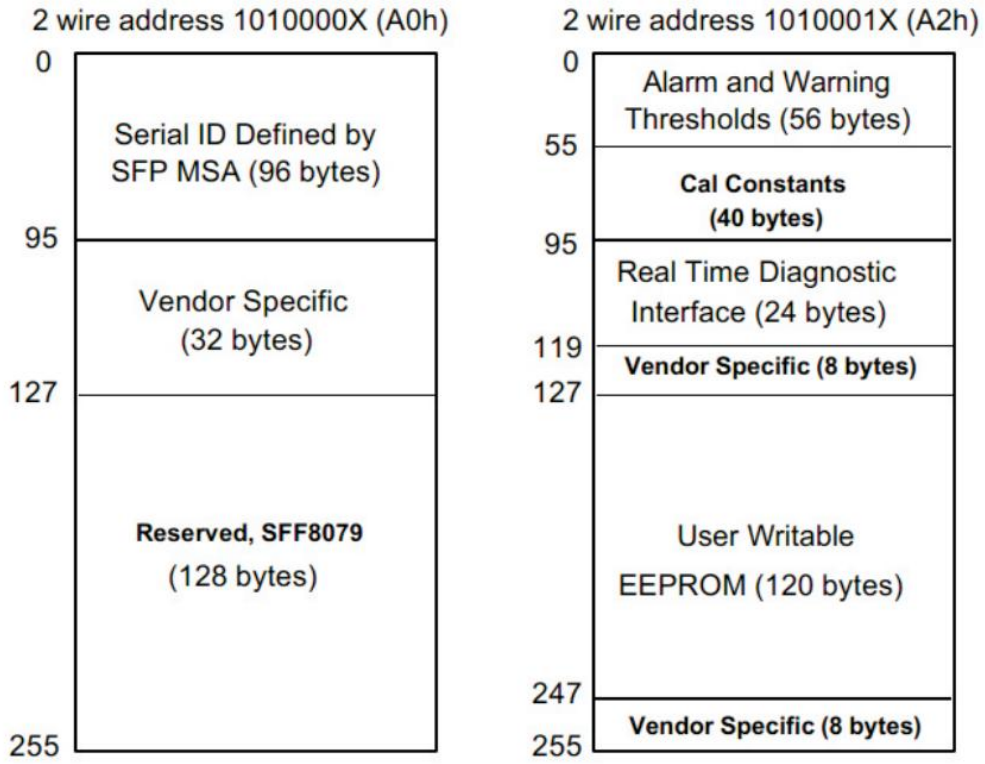
Parameter	Symbol	Min.	Typ.	Max.	Unit	Note
Transmitter						
Average Output Power	POUT	-6		-0.5	dBm	
Extinction Ratio	ER	3.5			dB	
Center Wavelength	λc	840	850	860	nm	VCSEL Laser
Transmitter OFF Output Power	Poff			-45	dBm	
Receiver						
Receiver Sensitivity	SENS			-11.4	dBm	1
Receiver Overload		0.5			dBm	
Input Optical Wavelength	λC	840		860	nm	PIN-TIA
LOS De-assert	LOSD			-13	dBm	
LOS Assert	LOSA	-30			dBm	2
LOS Hysteresis		0.5	1.0		dB	

Note:

1. Class 1 Laser Safety per FDA/CDRH and IEC-825-1 regulations.
2. Measured with a PRBS 2^{31}-1 test pattern, @10Gb/s, BER<10^{-12} .

EEPROM Information

EEPROM memory map specific data field description is as below:

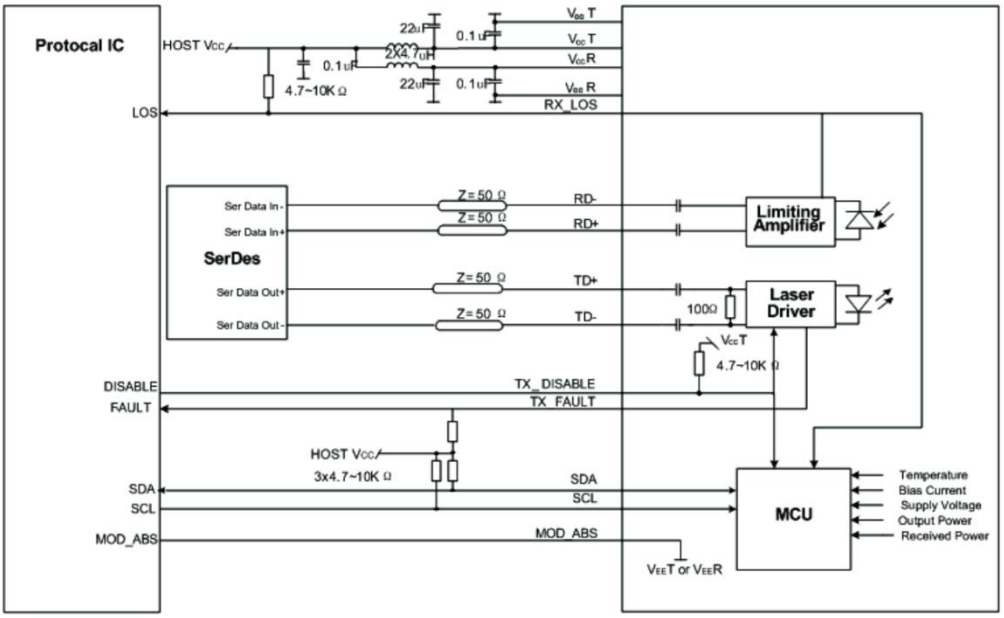


Digital Diagnostic Monitoring Interface

Five transceiver parameter values are monitored. The following table defines the monitored parameter's accuracy.

Parameter	Range	Accuracy	Calibration
Temperature	0 to +70°C (C)	±3°C	Internal
	-40 to +85°C (C)	±3°C	Internal
Voltage	2.97 to 3.63V	±3%	Internal
Bias Current	0 to 100mA	±10%	Internal
TX Power	-7 to 0dBm	±3dBm	Internal
RX Power	-12 to 1dBm	±3dBm	Internal

Recommend Circuit Schematic



Mechanical Specifications